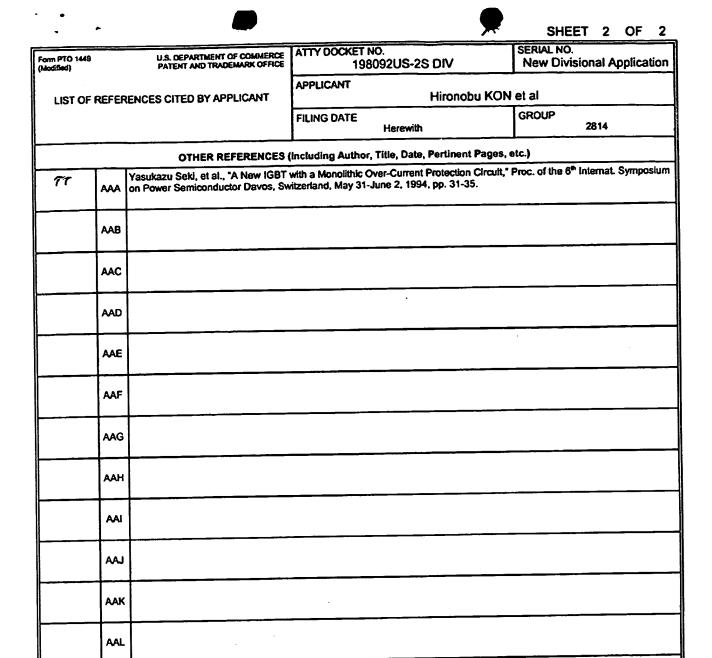
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LIST OF REFERENCES CITED BY APPLICANT			APPLICANT HIRONOBU KON, ET AL.						
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